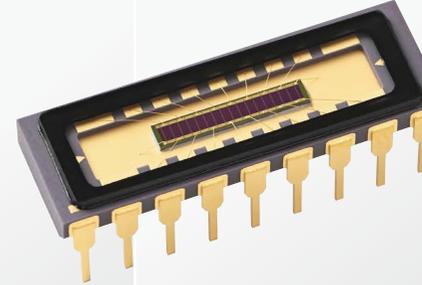
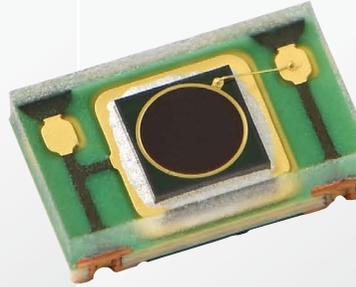


Supports various spectral response ranges in the infrared region

# Infrared detectors



## Supports various spectral response ranges in the infrared region

Infrared detectors are widely used in fields including measurement, analysis, industry, communications, agriculture, medicine, physical-and-chemical science, astronomy, and aerospace. Based on its long experience in optical technology, Hamamatsu provides a wide lineup of products for the infrared region.



When using infrared detectors, the following points should be taken into consideration for making a device selection.

## Spectral response

We offer detectors with various spectral responses ([P.5](#)). By cooling the element, the spectral response of InGaAs, InAs, InSb, and InAsSb shifts to the short-wavelength side.

## Response speed

Various detectors are available with different response speeds.

## Photosensitive area, number of elements

Various types are available, ranging from small to large photosensitive area sizes. We also offer multi-element types suitable for high-speed multi-channel spectrophotometry.

## Cooling

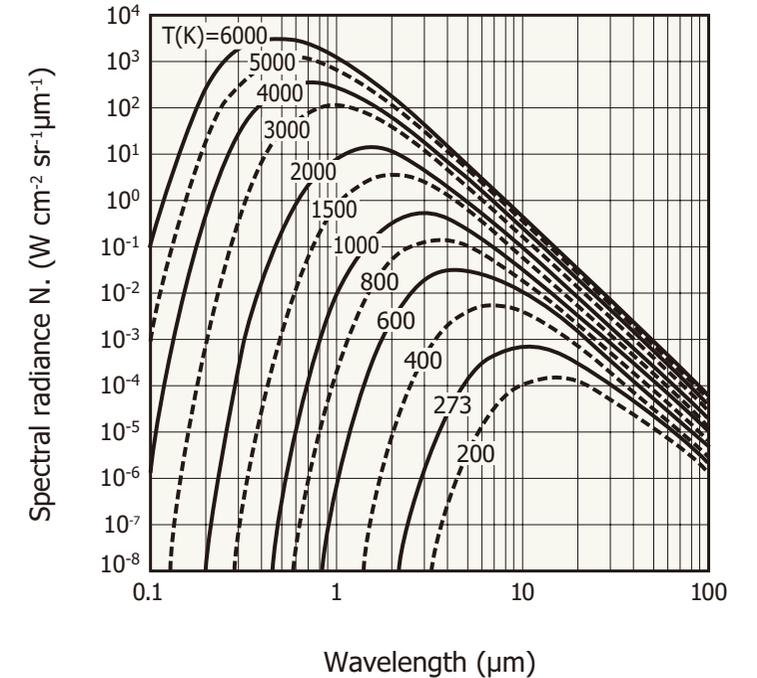
Besides the easy-to-use non-cooled type, we offer a TE-cooled type that does not require coolant, as well as a dewar type (cooled with liquid nitrogen) that realizes low noise.

## Object temperature

When selecting a detector based on the temperature of the object, it is necessary to consider the energy distribution (wavelength dependence of energy) radiated from the object. When the temperature of the object changes, its radiant energy distribution changes according to the law of black body radiation (Planck's law of radiation). (See the figure on the right.) The following relationship exists between the peak sensitivity wavelength  $\lambda_p$  ( $\mu\text{m}$ ) and the object temperature  $T$  (K).

$$\lambda_p \cdot T = 2897.9$$

## ● Law of black body radiation (Planck's law)

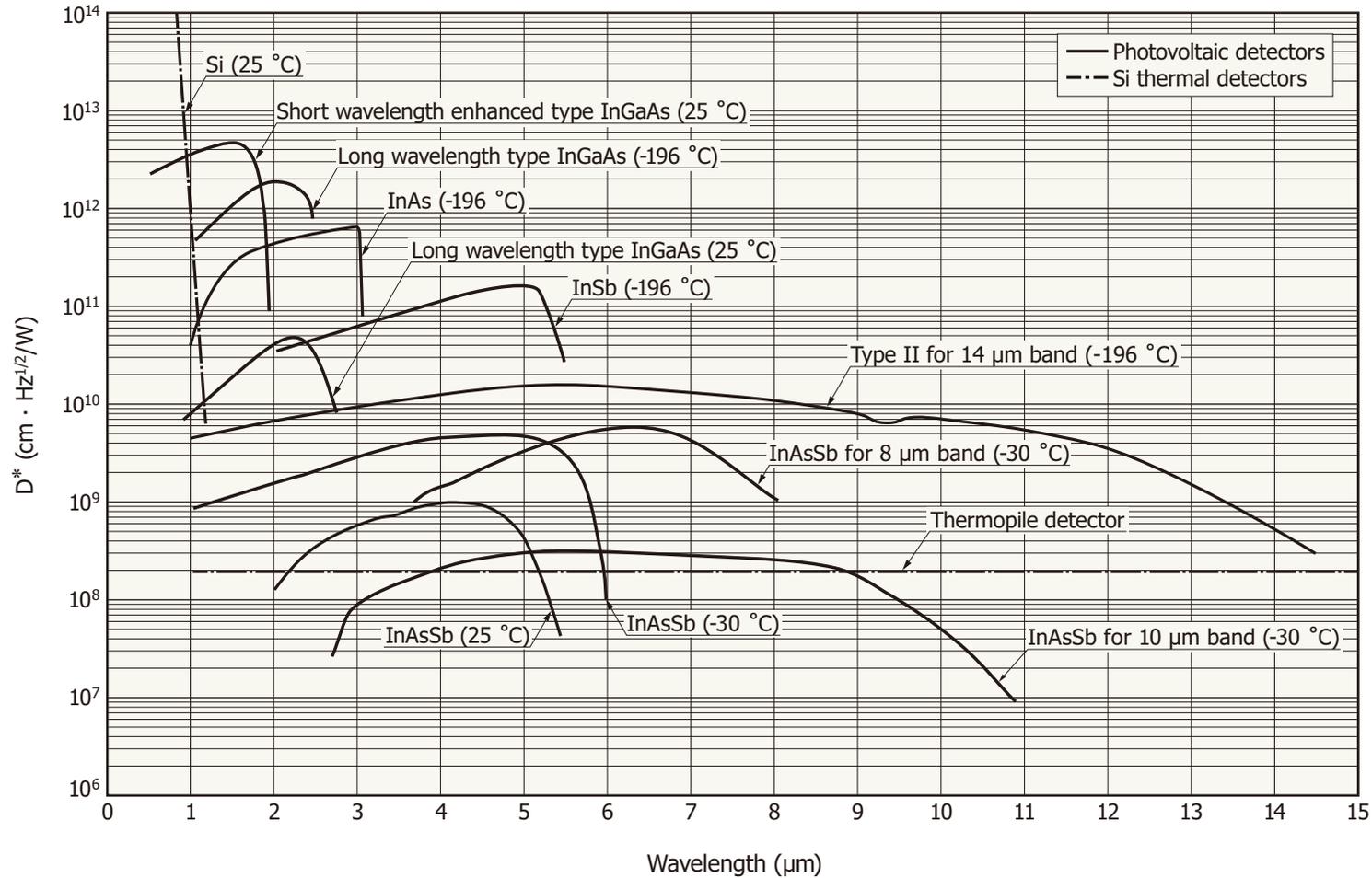


KIRDB0014EB

Product name	Spectral response range (μm)	Features	Main applications
<a href="#">InGaAs PIN photodiode</a>	0.5 to 1.7 μm	<ul style="list-style-type: none"> <li>High-speed response</li> <li>Various types of photosensitive areas, arrays, and packages available</li> <li>TE-cooled type available</li> </ul>	<ul style="list-style-type: none"> <li>Optical fiber communications</li> <li>Power meters</li> <li>Gas analysis</li> <li>Moisture meters</li> <li>NIR (near infrared) photometry</li> </ul>
	0.9 to 1.7 μm		
	0.9 to 1.9 μm		
	0.9 to 2.1 μm		
	0.9 to 2.6 μm		
<a href="#">InGaAs APD</a>	0.95 to 1.7 μm	<ul style="list-style-type: none"> <li>Low dark current</li> <li>Low capacitance</li> <li>High sensitivity</li> </ul>	<ul style="list-style-type: none"> <li>Distance measurement</li> <li>LiDAR</li> <li>OTDR</li> </ul>

Product name	Spectral response range (μm)	Features	Main applications
<a href="#">InAs photovoltaic detector</a>	1 to 3.8 μm	<ul style="list-style-type: none"> <li>Covers a spectral response range close to PbS but offers higher response speed</li> </ul>	<ul style="list-style-type: none"> <li>Gas measurement</li> <li>Infrared measurement</li> <li>FTIR</li> </ul>
<a href="#">InSb photovoltaic detector</a>	1 to 5.5 μm	<ul style="list-style-type: none"> <li>High sensitivity in the 3 to 5 μm band makes it suitable for analysis of gases such as CO<sub>2</sub>, SO<sub>x</sub>.</li> </ul>	<ul style="list-style-type: none"> <li>FTIR</li> <li>Gas measurement</li> <li>Radiation thermometers</li> <li>Flame detection</li> </ul>
<a href="#">InAsSb photovoltaic detector</a>	1 to 11 μm	<ul style="list-style-type: none"> <li>High-speed response, high sensitivity, and high reliability infrared detectors in the 5 μm, 8 μm, or 10 μm band</li> <li>Covers a spectral response range (5 μm band) close to PbSe but offers higher response speed</li> </ul>	<ul style="list-style-type: none"> <li>Gas measurement</li> <li>FTIR</li> <li>Radiation thermometers</li> <li>Laser monitors</li> </ul>
<a href="#">Type II superlattice infrared detector</a>	1 to 14.5 μm	<ul style="list-style-type: none"> <li>This sensor has expanded sensitivity up to the 14 μm band without using mercury or cadmium restricted by RoHS directive.</li> </ul>	<ul style="list-style-type: none"> <li>FTIR</li> <li>Gas measurement</li> <li>Radiation thermometers</li> </ul>
<a href="#">Thermopile detector</a>	3 to 5 μm	<ul style="list-style-type: none"> <li>Sensors that generate thermoelectromotive force in proportion to the incident infrared light energy</li> </ul>	<ul style="list-style-type: none"> <li>Gas measurement</li> <li>CO<sub>2</sub> density measurement</li> </ul>
<a href="#">Two-color detector</a>	Si + InGaAs	0.32 to 2.55 μm	<ul style="list-style-type: none"> <li>Spectrophotometers</li> <li>Laser monitors</li> <li>Flame monitors</li> <li>Radiation thermometers</li> </ul>
	Si + InAsSb	0.32 to 5.3 μm	
	InGaAs + InGaAs	0.9 to 2.55 μm	

● Spectral response (typical example)

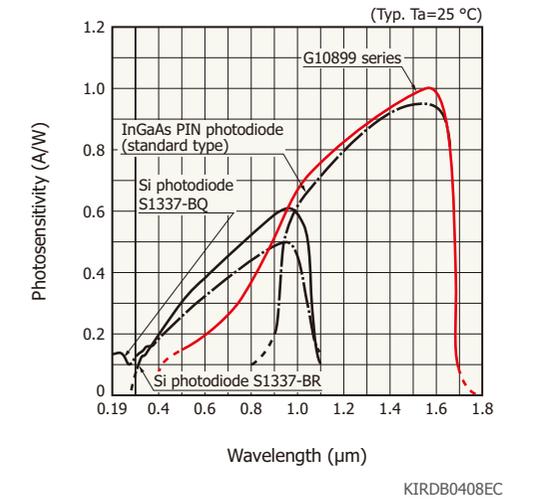


# Short wavelength enhanced type

(Typ. Ta=25 °C)

Type no.	Cooling	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ $V_R=1\text{ V}$ (MHz)	Package	Photo	Dedicated amplifier (sold separately)
<a href="#">G10899-003K</a>	Non-cooled	$\phi 0.3$	0.5 to 1.7	1.55	300	TO-18		<a href="#">C4159-03</a>
<a href="#">G10899-005K</a>		$\phi 0.5$			150			
<a href="#">G10899-01K</a>		$\phi 1$			45			
<a href="#">G10899-02K</a>		$\phi 2$			10	TO-5		
<a href="#">G10899-03K</a>		$\phi 3$			5			

## ● Spectral response



# Standard type

Metal package

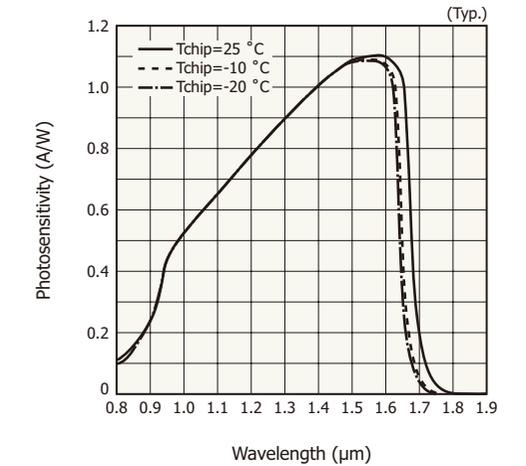
Various sizes of photosensitive areas are available.

(Typ.  $T_a=25\text{ }^\circ\text{C}$ , unless otherwise noted)

Type no.	Cooling	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ (MHz)	Package	Photo	Options (sold separately)
<a href="#">G12180-003A</a>	Non-cooled	$\phi 0.3$	0.9 to 1.7	1.55	600 ( $V_R=5\text{ V}$ )	TO-18		<a href="#">C4159-03</a>
<a href="#">G12180-005A</a>		$\phi 0.5$			200 ( $V_R=5\text{ V}$ )			
<a href="#">G12180-010A</a>		$\phi 1$			60 ( $V_R=5\text{ V}$ )			
<a href="#">G12180-020A</a>		$\phi 2$			13 ( $V_R=1\text{ V}$ )	TO-5		
<a href="#">G12180-030A</a>		$\phi 3$			7 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-050A</a>		$\phi 5$			3 ( $V_R=1\text{ V}$ )	TO-8		
<a href="#">G8370-81*</a>		$\phi 1$			35 ( $V_R=1\text{ V}$ )	TO-18		
<a href="#">G8370-82*</a>		$\phi 2$			4 ( $V_R=1\text{ V}$ )	TO-5		
<a href="#">G8370-83*</a>		$\phi 3$			2 ( $V_R=1\text{ V}$ )			
<a href="#">G8370-85*</a>		$\phi 5$			0.6 ( $V_R=1\text{ V}$ )	TO-8		
<a href="#">G12180-110A</a>	One-stage TE-cooled ( $T_{\text{chip}}=-10\text{ }^\circ\text{C}$ )	$\phi 1$	0.9 to 1.67	1.55	40 ( $V_R=1\text{ V}$ )	TO-8		<a href="#">C4159-03</a> <a href="#">A3179</a> <a href="#">C1103-04</a>
<a href="#">G12180-120A</a>		$\phi 2$			13 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-130A</a>		$\phi 3$			7 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-150A</a>		$\phi 5$			3 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-210A</a>	Two-stage TE-cooled ( $T_{\text{chip}}=-20\text{ }^\circ\text{C}$ )	$\phi 1$	0.9 to 1.65	1.55	40 ( $V_R=1\text{ V}$ )	TO-8		<a href="#">C4159-03</a> <a href="#">A3179-01</a> <a href="#">C1103-04</a>
<a href="#">G12180-220A</a>		$\phi 2$			13 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-230A</a>		$\phi 3$			7 ( $V_R=1\text{ V}$ )			
<a href="#">G12180-250A</a>		$\phi 5$			3 ( $V_R=1\text{ V}$ )			
<a href="#">G6854-01</a>	Non-cooled	$\phi 0.08$	0.9 to 1.7	1.55	2000 ( $V_R=5\text{ V}$ )	With CD lens TO-18		—

\* Low PDL type

## ● Spectral response



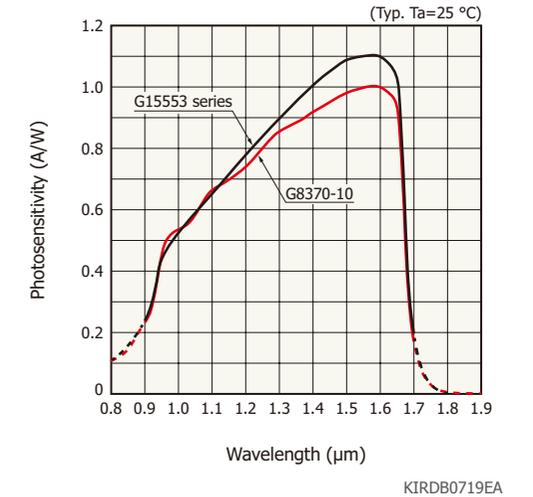
# Standard type

Ceramic package, plastic package

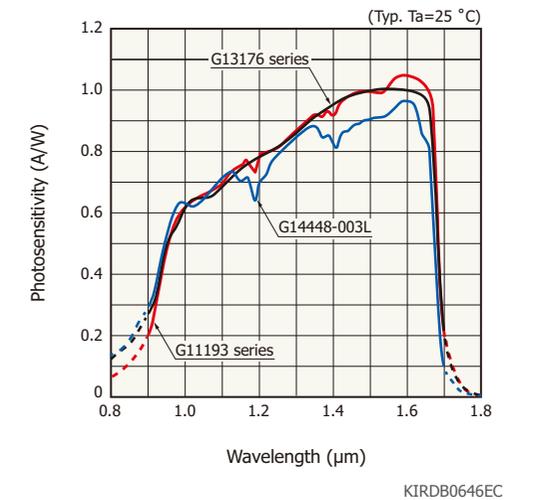
Type no.	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ $V_R=5\text{ V}$ (MHz)	Package	Photo (Typ. $T_a=25\text{ }^\circ\text{C}$ )
<a href="#">G8370-10</a>	$\phi 10$	0.9 to 1.7	1.55	0.1*	Ceramic	
<a href="#">G15553-003C</a>	$\phi 0.3$			600	Ceramic (unsealed, surface mount type)	
<a href="#">G15553-005C</a>	$\phi 0.5$			200		
<a href="#">G15553-010C</a>	$\phi 1$			60		
<a href="#">G11193-02R</a>	$\phi 0.2$			1000	Ceramic (surface mount type)	
<a href="#">G11193-03R</a>	$\phi 0.3$			500		
<a href="#">G11193-10R</a>	$\phi 1$			60		
<a href="#">G13176-003P</a>	$\phi 0.3$			600	Plastic COB (surface mount type)	
<a href="#">G13176-010P</a>	$\phi 1$			60		
<a href="#">G14448-003L</a>	$\phi 0.3$			600	Plastic COB with lens (surface mount type)	

\*  $V_R=0\text{ V}$

● Spectral response  
[ G8370-10, G15553 series ]



[ G11193, G13176 series, G14448-003L ]

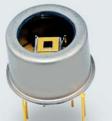


# Long wavelength type

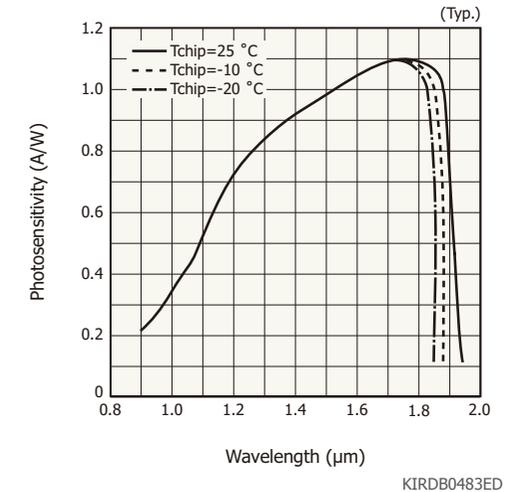
Peak sensitivity wavelength: 1.75  $\mu\text{m}$

These are suitable for light measurement around 1.7  $\mu\text{m}$ .

(Typ.  $T_a=25\text{ }^\circ\text{C}$ , unless otherwise noted)

Type no.	Cooling	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ $V_R=0\text{ V}$ (MHz)	Package	Photo	Options (sold separately)	
<a href="#">G12181-003K</a>	Non-cooled	$\phi 0.3$	0.9 to 1.9	1.75	90	TO-18		<a href="#">C4159-03</a>	
<a href="#">G12181-005K</a>		$\phi 0.5$			35				
<a href="#">G12181-010K</a>		$\phi 1$			10				
<a href="#">G12181-020K</a>		$\phi 2$			2.5	TO-5			
<a href="#">G12181-030K</a>		$\phi 3$			1.5				
<a href="#">G12181-103K</a>	One-stage TE-cooled ( $T_{\text{chip}}=-10\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 1.87		140	TO-8		<a href="#">C4159-03</a> <a href="#">A3179</a> <a href="#">C1103-04</a>	
<a href="#">G12181-105K</a>		$\phi 0.5$			50				
<a href="#">G12181-110K</a>		$\phi 1$			16				
<a href="#">G12181-120K</a>		$\phi 2$			3.5				
<a href="#">G12181-130K</a>		$\phi 3$			1.8				
<a href="#">G12181-203K</a>	Two-stage TE-cooled ( $T_{\text{chip}}=-20\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 1.85		150	TO-8		<a href="#">C4159-03</a> <a href="#">A3179-01</a> <a href="#">C1103-04</a>	
<a href="#">G12181-205K</a>		$\phi 0.5$			53				
<a href="#">G12181-210K</a>		$\phi 1$			17				
<a href="#">G12181-220K</a>		$\phi 2$			3.7				
<a href="#">G12181-230K</a>		$\phi 3$			1.9				

## ● Spectral response

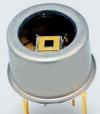


# Long wavelength type

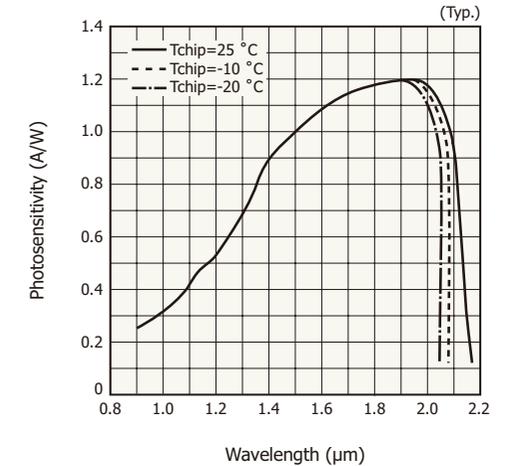
Peak sensitivity wavelength: 1.95  $\mu\text{m}$

These are suitable for optical measurement in the moisture absorption wavelength band in the 1.9  $\mu\text{m}$  band.

(Typ.  $T_a=25\text{ }^\circ\text{C}$ , unless otherwise noted)

Type no.	Cooling	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ $V_R=0\text{ V}$ (MHz)	Package	Photo	Options (sold separately)
<a href="#">G12182-003K</a>	Non-cooled	$\phi 0.3$	0.9 to 2.1	1.95	90	TO-18		<a href="#">C4159-03</a>
<a href="#">G12182-005K</a>		$\phi 0.5$			35			
<a href="#">G12182-010K</a>		$\phi 1$			10			
<a href="#">G12182-020K</a>		$\phi 2$			2.5	TO-5		
<a href="#">G12182-030K</a>		$\phi 3$			1.5			
<a href="#">G12182-103K</a>	One-stage TE-cooled ( $T_{\text{chip}}=-10\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 2.07	1.95	140	TO-8		<a href="#">C4159-03</a> <a href="#">A3179</a> <a href="#">C1103-04</a>
<a href="#">G12182-105K</a>		$\phi 0.5$			50			
<a href="#">G12182-110K</a>		$\phi 1$			16			
<a href="#">G12182-120K</a>		$\phi 2$			3.5			
<a href="#">G12182-130K</a>		$\phi 3$			1.8			
<a href="#">G12182-203K</a>	Two-stage TE-cooled ( $T_{\text{chip}}=-20\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 2.05	1.95	150	TO-8		<a href="#">C4159-03</a> <a href="#">A3179-01</a> <a href="#">C1103-04</a>
<a href="#">G12182-205K</a>		$\phi 0.5$			53			
<a href="#">G12182-210K</a>		$\phi 1$			17			
<a href="#">G12182-220K</a>		$\phi 2$			3.7			
<a href="#">G12182-230K</a>		$\phi 3$			1.9			

## ● Spectral response



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# Long wavelength type

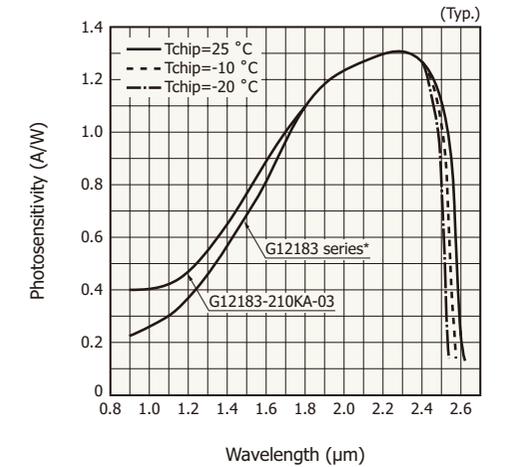
Peak sensitivity wavelength: 2.3  $\mu\text{m}$

These are suitable for NIR (near infrared) spectrometers.

(Typ.  $T_a=25\text{ }^\circ\text{C}$ , unless otherwise noted)

Type no.	Cooling	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Cutoff frequency $f_c$ $V_R=0\text{ V}$ (MHz)	Package	Photo	Options (sold separately)	
<a href="#">G12183-003K</a>	Non-cooled	$\phi 0.3$	0.9 to 2.6	2.3	50	TO-18		<a href="#">C4159-03</a>	
<a href="#">G12183-005K</a>		$\phi 0.5$			20				
<a href="#">G12183-010K</a>		$\phi 1$			6				
<a href="#">G12183-020K</a>		$\phi 2$			1.5	TO-5			
<a href="#">G12183-030K</a>		$\phi 3$			0.8				
<a href="#">G12183-103K</a>	One-stage TE-cooled ( $T_{\text{chip}}=-10\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 2.57		70	TO-8		<a href="#">C4159-03</a> <a href="#">A3179</a> <a href="#">C1103-04</a>	
<a href="#">G12183-105K</a>		$\phi 0.5$			25				
<a href="#">G12183-110K</a>		$\phi 1$			7				
<a href="#">G12183-120K</a>		$\phi 2$			2				
<a href="#">G12183-130K</a>		$\phi 3$			0.9				
<a href="#">G12183-203K</a>	Two-stage TE-cooled ( $T_{\text{chip}}=-20\text{ }^\circ\text{C}$ )	$\phi 0.3$	0.9 to 2.55		75	TO-8		<a href="#">C4159-03</a> <a href="#">A3179-01</a> <a href="#">C1103-04</a>	
<a href="#">G12183-205K</a>		$\phi 0.5$			28				
<a href="#">G12183-210K</a>		$\phi 1$			8				
<a href="#">G12183-220K</a>		$\phi 2$			2.3				
<a href="#">G12183-230K</a>		$\phi 3$			1				
<a href="#">G12183-210KA-03</a>		$\phi 1$		4	TO-66				

## Spectral response



\* Excluding G12183-210KA-03

KIRDB0491EF

# InGaAs PIN photodiode arrays

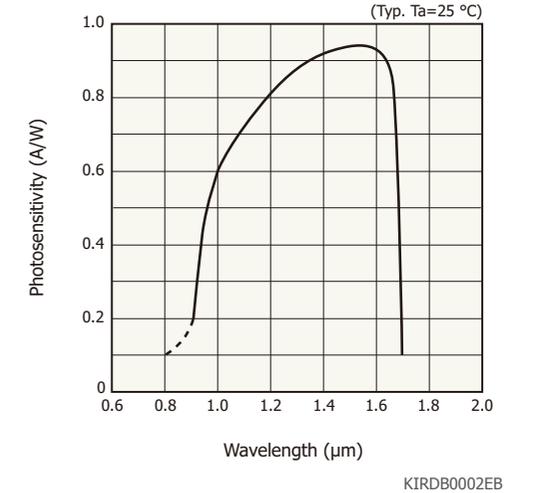
4-segmented type and 16, 32, 40, 46-element arrays are available.

(Typ. Ta=25 °C)

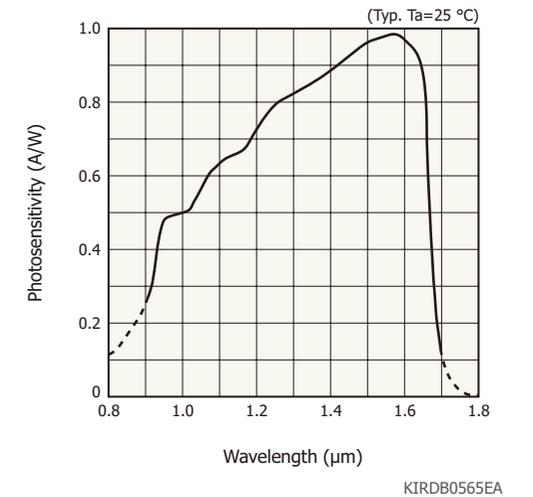
Type no.	Photosensitive area (mm)	Number of elements	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Package	Photo
<a href="#">G6849-01</a>	$\phi 1$	4-segment	0.9 to 1.7	1.55	TO-5	
<a href="#">G6849</a>	$\phi 2$	4-segment				
<a href="#">G7151-16</a>	0.08 x 0.2	16 elements				
<a href="#">G12430-016D</a>	0.45 x 1.0	16 elements				
<a href="#">G12430-032D</a>	0.2 x 1.0	32 elements				
<a href="#">G12430-046D</a>	0.2 x 1.0	46 elements				
<a href="#">G8909-01</a>	$\phi 0.08$	40 elements			Ceramic (unsealed)	

## ● Spectral response

[ G6849 series, G7151-16, G8909-01 ]



[ G12430 series ]



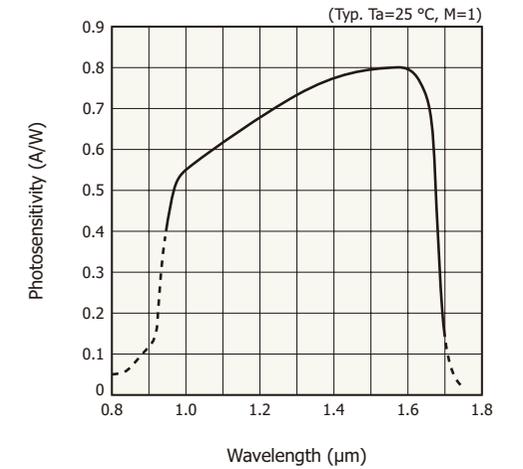
# InGaAs APD

The G14858-0020AA is used for distance measurement, low-light-level detection, and so on.

(Typ. Ta=25 °C)

Type no.	Photosensitive area (mm)	Spectral response range (μm)	Breakdown voltage max. ID=100 μA (V)	Cutoff frequency RL=50 Ω (MHz)	Terminal capacitance (pF)	Gain λ=1.55 μm	Package	Photo
<a href="#">G14858-0020AA</a>	φ0.2	0.95 to 1.7	80	900	2.0	30	TO-18	

## ● Spectral response

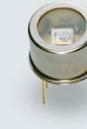


KAPDB0417EA

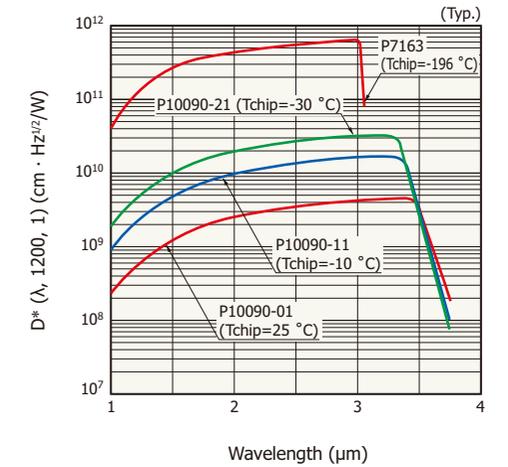
# InAs photovoltaic detectors

The InAs photovoltaic detectors are low-noise, high-speed response infrared detectors that can detect up to around 3.5  $\mu\text{m}$ .

(Typ.)

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Package	Photo	Options (sold separately)
<a href="#">P10090-01</a>	Non-cooled	$\phi 1$	3.65	3.35	TO-5		<a href="#">C4159-07</a>
<a href="#">P10090-11</a>	One-stage TE-cooled (Tchip=-10 °C)		3.55	3.30	TO-8		<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-06</a>
<a href="#">P10090-21</a>	Two-stage TE-cooled (Tchip=-30 °C)		3.45	3.25			<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-06</a>
<a href="#">P7163</a>	Liquid nitrogen (Tchip=-196 °C)		3.10	3.00	Metal dewar		<a href="#">C4159-05</a>

## ● Spectral response



KIRDB0356EE

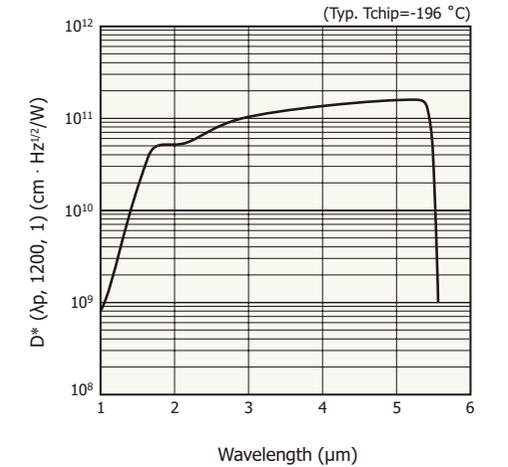
# InSb photovoltaic detectors

These are the most sensitive and fastest response detectors among our products in 5 μm band.

(Typ.)

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ (μm)	Peak sensitivity wavelength $\lambda_p$ (μm)	Package	Photo	Dedicated amplifier (sold separately)
<a href="#">P5968-060</a>	Liquid nitrogen (Tchip=-196 °C)	φ0.6	5.5	5.3	Metal dewar		<a href="#">C4159-01</a>
<a href="#">P5968-100</a>		φ1					<a href="#">C4159-04</a>
<a href="#">P5968-200</a>		φ2					
<a href="#">P5968-300</a>		φ3					Custom product

## ● Spectral response

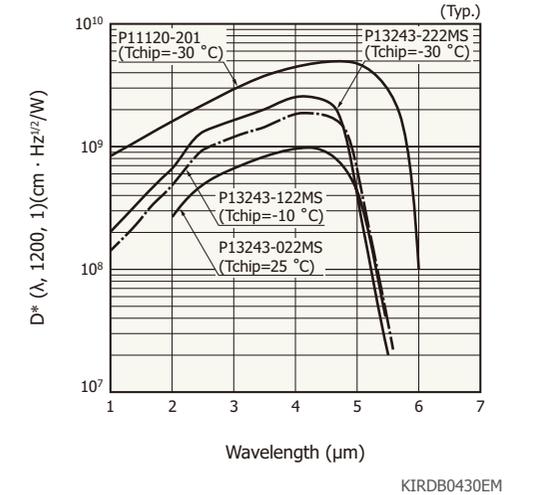


# Front-illuminated type

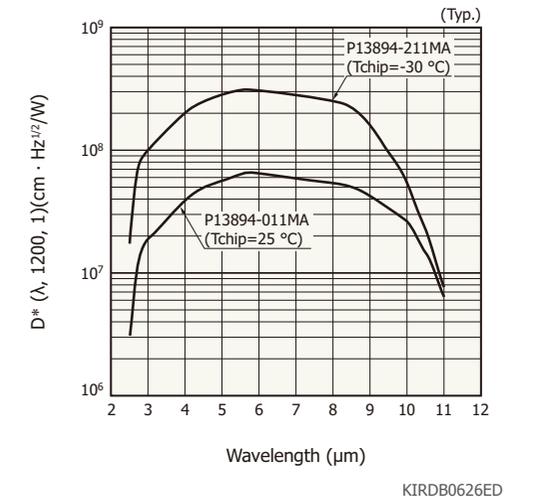
These are InAsSb photovoltaic detectors with cutoff wavelengths of 5 μm band or 10 μm band. The TE-cooled type capable of stable S/N measurement are available.

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ (μm)	Peak sensitivity wavelength $\lambda_p$ (μm)	Package	Photo	Options (sold separately)
<a href="#">P11120-201</a>	Two-stage TE-cooled (Tchip=-30 °C)	φ1	5.9	4.9	TO-8		<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-07</a>
<a href="#">P13243-022MS</a>	Non-cooled	2 × 2	5.3	4.1	TO-5		<a href="#">C4159-01</a>
<a href="#">P13243-122MS</a>	One-stage TE-cooled (Tchip=-10 °C)		TO-8			<a href="#">A3179</a> <a href="#">C1103-04</a> <a href="#">C4159-01</a>	
<a href="#">P13243-222MS</a>	Two-stage TE-cooled (Tchip=-30 °C)		TO-8			<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-01</a>	
<a href="#">P13894-011MA</a>	Non-cooled		1 × 1		11.0	TO-5	
<a href="#">P13894-211MA</a>	Two-stage TE-cooled (Tchip=-30 °C)	10.2		TO-8		<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-01</a>	

## ● Spectral response [ P11120-201, P13243 series ]



## [ P13894 series ]



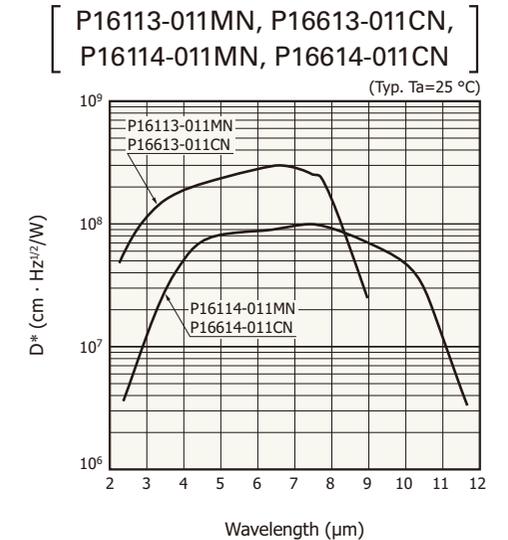
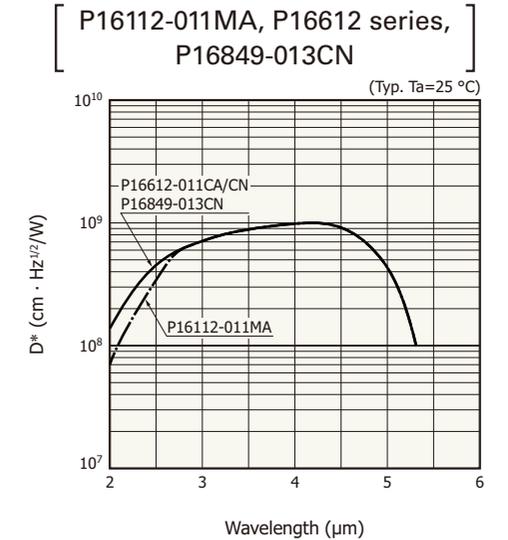
# Back-illuminated type

The back-illuminated type InAsSb photovoltaic detectors achieve cutoff wavelength of 5 μm, 8 μm, or 10 μm using Hamamatsu's unique crystal growth technology. Compared to the front-illuminated type, they achieve high sensitivity and improve the temperature characteristics of sensitivity.

(Typ.)

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength λ <sub>c</sub> (μm)	Peak sensitivity wavelength λ <sub>p</sub> (μm)	Package	Photo	Dedicated amplifier (sold separately)
<a href="#">P16112-011MA</a>	Non-cooled	0.7 × 0.7	5.3	4.1	TO-46		<a href="#">C4159-01</a>
<a href="#">P16612-011CA</a>					Ceramic (Surface mount type)		
<a href="#">P16612-011CN</a>							
<a href="#">P16113-011MN</a>			8.3	6.5	TO-5		
<a href="#">P16613-011CN</a>					Ceramic (Surface mount type)		
<a href="#">P16114-011MN</a>			11	7.4	TO-5		
<a href="#">P16614-011CN</a>		Ceramic (Surface mount type)					
<a href="#">P16849-013CN</a>		0.7 × 0.7 (two-element)	5.3	4.1			

## ● Spectral response



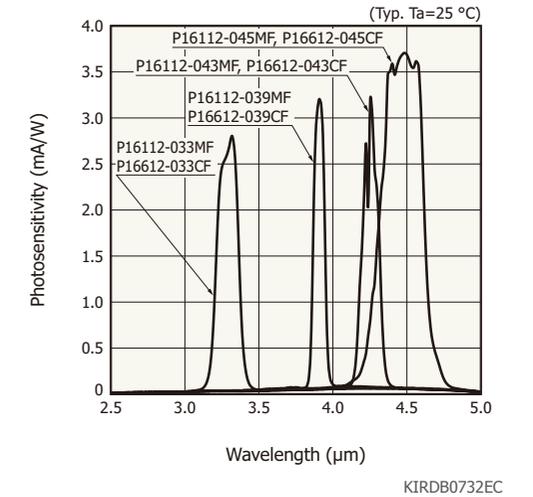
# With band-pass filter

These are back-illuminated type InAsSb photovoltaic detectors that use a band-pass filter (center wavelength: 3.3  $\mu\text{m}$ , 3.9  $\mu\text{m}$ , 4.26  $\mu\text{m}$ , 4.45  $\mu\text{m}$ ) for the window material. They are suitable for gas measurement ( $\text{CH}_4$ ,  $\text{CO}_2$ ) and flame detection.

Type no.	Cooling	Photosensitive area (mm)	Window material*	Package	Photo	Dedicated amplifier (sold separately)			
<a href="#">P16112-033MF</a>	Non-cooled	0.7 × 0.7	BPF (3.3 $\mu\text{m}$ )	Ceramic (Surface mount type)		<a href="#">C4159-01</a>			
<a href="#">P16612-033CF</a>									
<a href="#">P16112-039MF</a>			BPF (3.9 $\mu\text{m}$ )						
<a href="#">P16612-039CF</a>									
<a href="#">P16112-043MF</a>			BPF (4.26 $\mu\text{m}$ )						
<a href="#">P16612-043CF</a>									
<a href="#">P16112-045MF</a>			BPF (4.45 $\mu\text{m}$ )						
<a href="#">P16612-045CF</a>									
<a href="#">P16849-011CF</a>			0.7 × 0.7 (two-element)		0.7 × 0.7 (two-element)		BPF (3.3 $\mu\text{m}$ )		-
<a href="#">P16849-012CF</a>							BPF (3.9 $\mu\text{m}$ )		
	BPF (3.9 $\mu\text{m}$ )								
BPF (4.26 $\mu\text{m}$ )									

\* BPF: band-pass filter

## ● Spectral response



## With lens

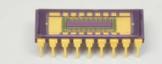
This is an InAsSb photovoltaic detector that achieves high sensitivity by mounting a lens on a chip with a back-illuminated structure. It is an electronically cooled type that provides a stable S/N.

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Package	Photo	Options (sold separately)
<a href="#">P12691-201G</a>	Two-stage TE-cooled ( $T_{\text{chip}}=-30\text{ }^\circ\text{C}$ )	$\phi 1$	8.3	6.7	TO-8		<a href="#">A3179-01</a> <a href="#">C1103-04</a> <a href="#">C4159-07</a>

(Typ.)

## Arrays

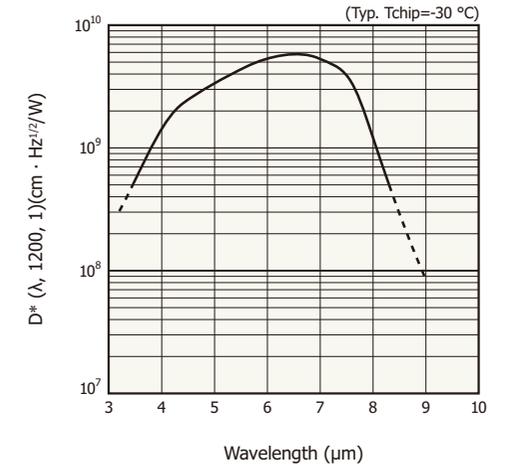
These are InAsSb arrays in DIP ceramic packages. Simultaneous measurement and wide range measurement are possible.

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Package	Photo	Dedicated amplifier (sold separately)
<a href="#">P15742-016DS</a>	Non-cooled	0.45 × 0.7 (16 elements)	5.3	4.1	Ceramic		—
<a href="#">P15742-046DS</a>		0.2 × 0.7 (46 elements)					

(Typ.)

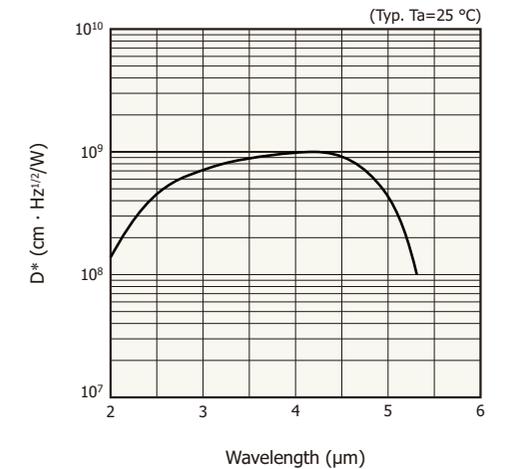
### ● Spectral response

[ P12691-201G ]



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[ P15742 series ]

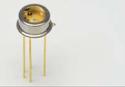


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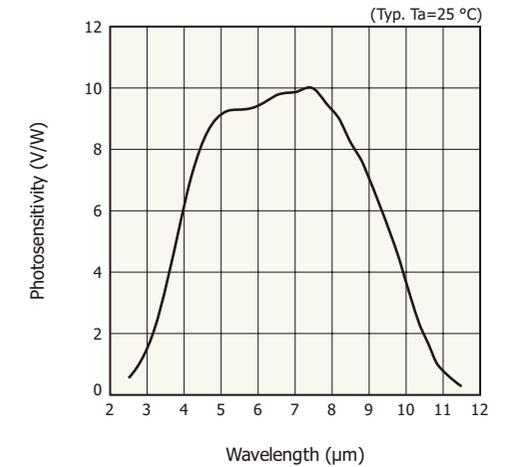
# InAsSb photovoltaic detector with preamp

It is a compact infrared detector that integrates an InAsSb photovoltaic detector (up to 11  $\mu\text{m}$ ) and a preamp. It is approximately 1/200 th the size of previous module products, and achieves a response speed of 100 MHz, which is twice as fast.

(Typ.)

Type no.	Photosensitive area (mm)	Cutoff wavelength $\lambda_c$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Frequency characteristics		Package	Photo
				FcL	FcH (MHz)		
<a href="#">P16702-011MN</a>	0.7 × 0.7	11	7.4	DC	100	TO-5	

## ● Spectral response



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# Type II superlattice infrared detectors

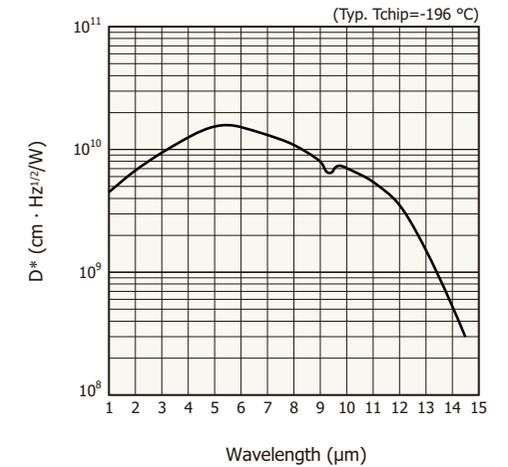
## Type II superlattice infrared detector

The P15409-901 is a type II superlattice infrared detector with sensitivity expanded to the 14 μm band using Hamamatsu's unique crystal growth technology and process technology. This product is an environmentally friendly infrared detector and does not use mercury or cadmium, which are substances restricted by the RoHS directive. It is a replacement for conventional products that contain these substances.

Type no.	Cooling	Photosensitive area (mm)	Cutoff wavelength* λc (μm)	Peak sensitivity wavelength λp (μm)	Package	Photo	Dedicated amplifier (sold separately)
<a href="#">P15409-901</a>	Liquid nitrogen (Tchip=-196 °C)	φ0.1	14.5	5.4	Metal dewar		<a href="#">C4159-01</a>

\* Wavelength at which signal/noise = 1

## ● Spectral response



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## Infrared detector module with preamp

This is an amplifier-integrated module that can detect infrared light simply by connecting a DC power supply.

Type no.	Detector	Photosensitive area (mm)	Cooling	Measurement condition	Cutoff wavelength λc (μm)	Peak sensitivity wavelength λp (μm)	Photo
				Chip temperature (°C)			
<a href="#">C15780-401</a>	Type II superlattice (P15409-901)	φ0.1	Liquid nitrogen	-196	14.5	5.4	

# Thermopile detectors (thermal detectors)

## Single element

These are high-sensitivity Si thermopile detectors suitable for gas density measurement or the like. By attaching a band-pass filter to the thermopile detector, it is possible to measure the concentration of various gases. The T15570 is suitable for flame detection. (Typ.)

Type no.	Number of elements	Photosensitive area (mm)	Window material	Spectral response range (μm)	Package	Photo
<a href="#">T11361-01*</a>	1	1.2 × 1.2	Si with AR coating	3 to 5	TO-18	
<a href="#">T15770</a>			With band-pass filter	4.45		

\* Built-in thermistor

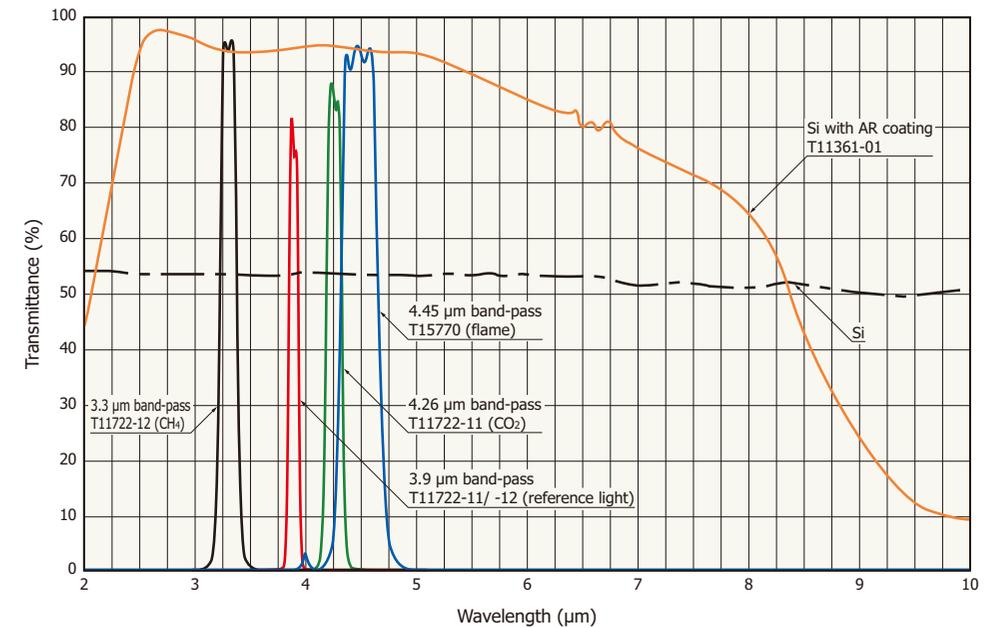
## Dual element

These dual type thermopile detectors were developed to measure concentration of carbon dioxide (CO<sub>2</sub>) and methane (CH<sub>4</sub>) with high accuracy. They consist of two high-sensitivity Si thermopile chips and two band-pass filters so that two wavelengths can be detected simultaneously. (Typ.)

Type no.	Number of elements	Photosensitive area (mm)	Window material	Spectral response range (μm)	Package	Photo
<a href="#">T11722-11</a>	2	1.2 × 1.2 (per element)	With band-pass filter	Reference light: 3.9 CO <sub>2</sub> : 4.26	TO-5	
<a href="#">T11722-12</a>				Reference light: 3.9 CH <sub>4</sub> : 3.3		

## ● Spectral response (typical example)

Since thermopile detectors have no wavelength dependence, their spectral response is determined by the transmittance characteristics of window materials. Spectral transmittance characteristics of typical window materials are shown below. Please contact our sales office if you wish to replace a window material with the one shown below for thermopile detectors.



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# Two-color detectors

These sensors have two photosensors with different spectral response ranges arranged on the top and bottom of the same optical axis. They realize a wide spectral response range. The TE-cooled types improve the S/N and enable high accuracy measurement by cooling the element and keeping the temperature constant.

(Typ.)

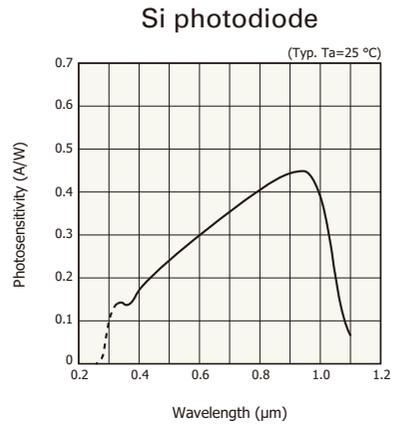
Type no.	Cooling	Detector	Photosensitive area (mm)	Spectral response range $\lambda$ ( $\mu\text{m}$ )	Peak sensitivity wavelength $\lambda_p$ ( $\mu\text{m}$ )	Photosensitivity S $\lambda=\lambda_p$ (A/W)	Package	Photo	Options (sold separately)		
<a href="#">K1713-003</a>	Non-cooled	Si	2.4 × 2.4	0.32 to 5.3	0.94	0.45	TO-5		<a href="#">C9329-01</a>		
		InAsSb	0.7 × 0.7			4.0			0.0039	<a href="#">C4159-01</a>	
<a href="#">K1713-05</a>		Si	2.4 × 2.4	0.32 to 1.7	0.94	0.45			<a href="#">C9329-01</a> <a href="#">C4159-03</a>		
		InGaAs	φ0.5			1.55				0.55	
<a href="#">K1713-08</a>		Si	2.4 × 2.4	0.32 to 2.6	0.94	0.45					
		InGaAs	φ1			2.3				0.60	
<a href="#">K1713-09</a>		Si	2.4 × 2.4	0.32 to 1.7	0.94	0.45					
		InGaAs	φ1			1.55				0.55	
<a href="#">K11908-010K</a>		InGaAs	2.4 × 2.4	0.9 to 2.55	1.55	0.95				<a href="#">C4159-03</a>	
		InGaAs	φ1			2.1					1.0
<a href="#">K13085-010K</a>		InGaAs	2.4 × 2.4	0.9 to 1.85	1.55	0.95					
		InGaAs	φ1			1.75					0.8
<a href="#">K3413-05</a>	One-stage TE-cooled (Tchip=-10 °C)	Si	2.4 × 2.4	0.32 to 1.67	0.94	0.45	TO-8				<a href="#">C9329-01</a> <a href="#">C4159-03</a> <a href="#">A3179-03</a> <a href="#">C1103-04</a>
		InGaAs	φ0.5			1.55					
<a href="#">K3413-08</a>		Si	2.4 × 2.4	0.32 to 2.57	0.94	0.45					
		InGaAs	φ1			2.3			0.60		
<a href="#">K3413-09</a>		Si	2.4 × 2.4	0.32 to 1.67	0.94	0.45					
		InGaAs	φ1			1.55			0.55		
<a href="#">K12728-010K</a>	Non-cooled	Si	2.4 × 2.4	0.32 to 1.7	0.96	0.45	Ceramic (surface mount type)		-		
		InGaAs	φ1			1.55					0.55
		InGaAs	2.4 × 2.4	0.9 to 2.55	1.55	0.95					
<a href="#">K12729-010K</a>		InGaAs	φ1			2.1				1.0	

# Two-color detectors

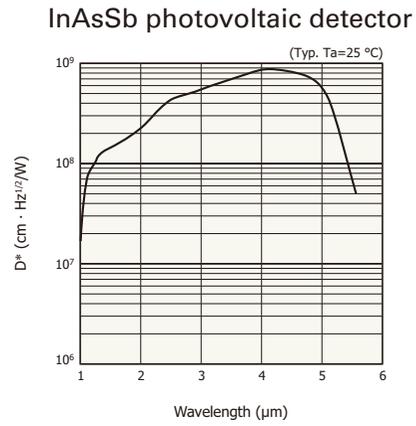
● Spectral response

[ K1713-003 ]

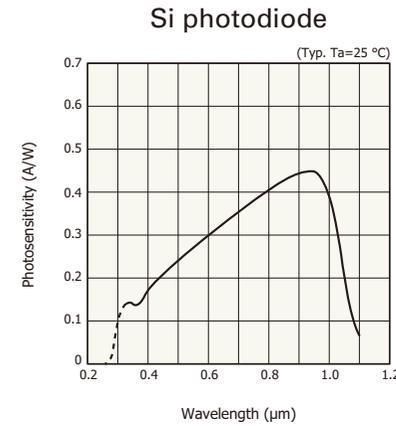
[ K1713-05/-08/-09 ]



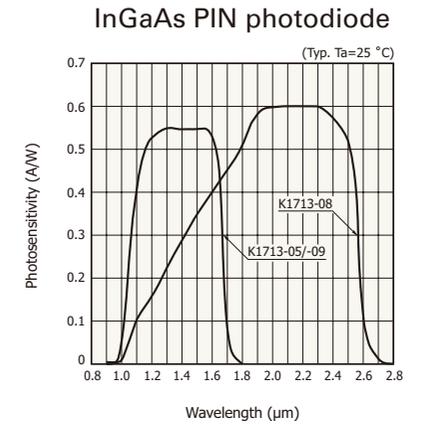
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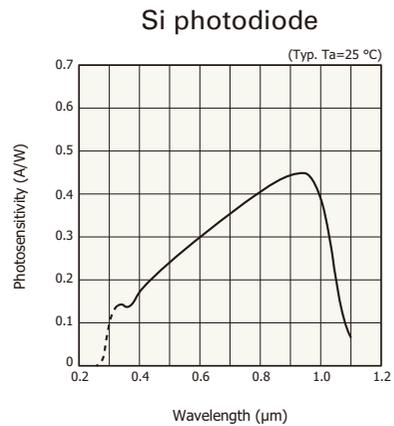


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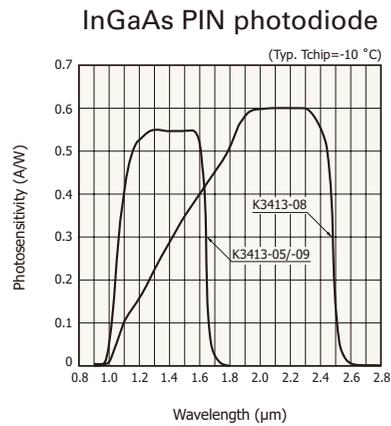
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[ K11908-010K, K13085-010K, K12729-010K ]

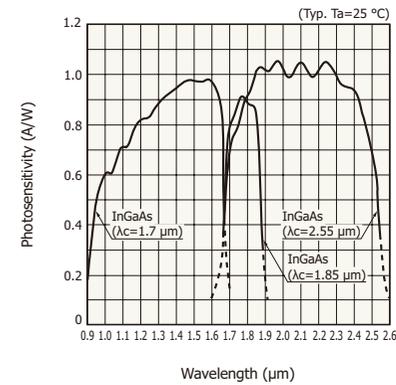
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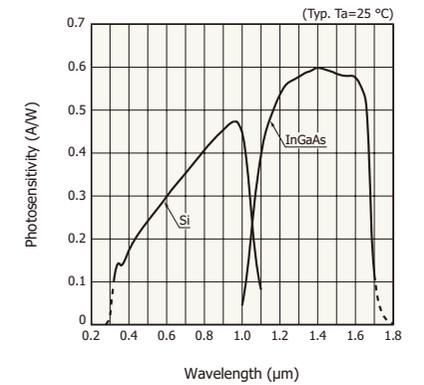
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KIRDB0212EB



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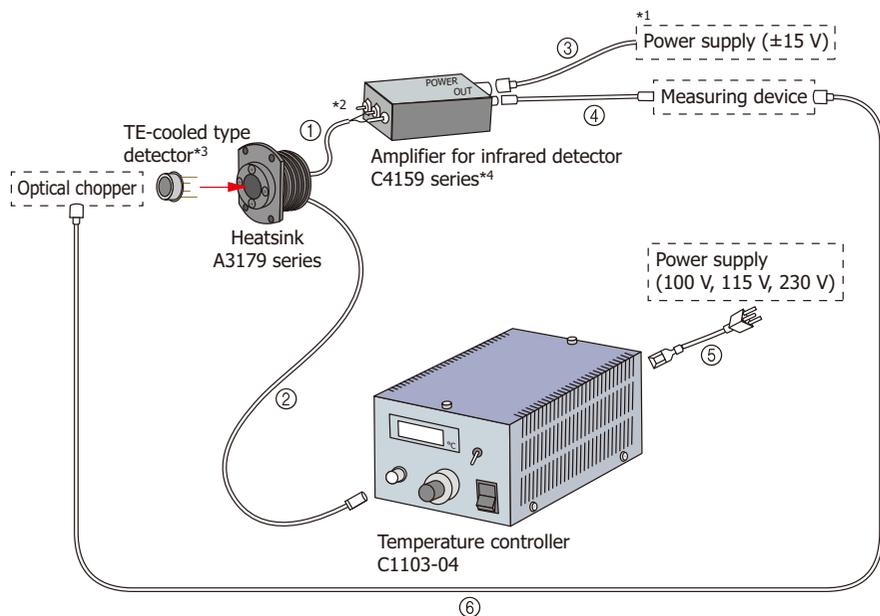
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# Accessories for infrared detectors

Hamamatsu provides the following accessories for infrared detectors.

Product name	Type no.	Overview
Temperature controller	<a href="#">C1103-04</a>	The temperature of the TE-cooler inside the detector can be set. Compatible with one-stage and two-stage TE-cooled InAsSb/InAs photovoltaic detectors and InGaAs/Si photodiodes
Valve operator for metal dewar	<a href="#">A3515</a>	The valve operator can be used to re-evacuate the metal dewar. Please be aware of that the detector performance is not guaranteed after re-evacuation at the customer side.
Heatsink (for TE-cooled detector TO-8/TO-3 package)	<a href="#">A3179 series</a>	This heatsink is designed for TE-cooled detectors in 6-pin TO-8 packages and TO-3 packages.

## ● Connection example



## Cable

Cable no.	Cable	Approx. length	Note
①	Coaxial cable (for signals)	2 m	Supplied with heatsink A3179 series. Make the cable as short as possible. (approx. 10 cm is desirable)
②	4-conductor cable (with a connector) A4372-05	3 m	Supplied with temperature controller C1103 series. It is also sold separately.
③	4-conductor cable (with a connector) A4372-02	2 m	Supplied with C4159 series amplifiers for infrared detectors and infrared detector modules with preamp (room temperature type). It is also sold separately.
④	BNC connector cable E2573	1 m	Sold separately
⑤	Power cable (for temperature controller)	1.9 m	Supplied with temperature controller C1103 series
⑥	Cable	-	It needs to be prepared by user side.

\*1: Attach the unterminated wire to a 3-4 pin connector or banana plug, then connect it to the power supply.

\*2: Soldering is required.

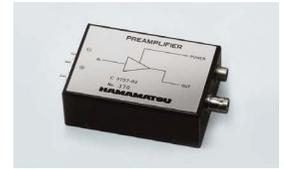
\*3: No dedicated socket is available. Soldering is required.

\*4: Refer to amplifiers for infrared detectors ([P.24](#)) for details.

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# Amplifiers for infrared detectors

These are low noise amplifiers for InSb, InAs, InAsSb, and InGaAs detectors.



Product name	Type no.	Conversion impedance 3 range switchable (V/A)	Frequency characteristics Amplifier only, -3 dB	Equivalent input noise current f=1 kHz (pA/Hz <sup>1/2</sup> )	External power supply (V)	Applicable detectors
Amplifier for photovoltaic detector	<a href="#">C4159-01</a>	10 <sup>8</sup> , 10 <sup>7</sup> , 10 <sup>6</sup>	DC to 100 kHz	0.15 (10 <sup>8</sup> , 10 <sup>7</sup> range) 0.65 (10 <sup>6</sup> range)	±15	Dewar type InSb (P5968-060/-100), non-cooled type InAsSb (P13243-022MS, P13894-011MA, P16112-011MA/-033MF/-039MF/-043MF/-045MF, P16612-011CA/-011CN/-033CF/-039CF/-043CF/-045CF, P16113-011MN, P16613-011CN, P16114-011MN, P16614-011CN), TE-cooled type InAsSb (P13243-122MS/-222MS, P13894-211MA), dewar Type II (P15409-901)
	<a href="#">C4159-04</a>	2 × 10 <sup>7</sup> , 2 × 10 <sup>6</sup> , 2 × 10 <sup>5</sup>	DC to 45 kHz	0.55	±15	Dewar type InSb (P5968-200)
	<a href="#">C4159-05</a>	10 <sup>8</sup> , 10 <sup>7</sup> , 10 <sup>6</sup>	DC to 15 kHz	0.15 (10 <sup>8</sup> , 10 <sup>7</sup> range) 0.65 (10 <sup>6</sup> range)	±15	Dewar type InAs (P7163)
	<a href="#">C4159-06</a>	10 <sup>6</sup> , 10 <sup>5</sup> , 10 <sup>4</sup>	DC to 100 kHz	6	±15	TE-cooled type InAs (P10090-11/-21)
	<a href="#">C4159-07</a>	10 <sup>6</sup> , 10 <sup>5</sup> , 10 <sup>4</sup>	DC to 100 kHz	10	±15	Non-cooled type InAs (P10090-01), TE-cooled type InAsSb (P11120-201, P12691-201G)
Amplifier for InGaAs PIN photodiode	<a href="#">C4159-03</a>	10 <sup>7</sup> , 10 <sup>6</sup> , 10 <sup>5</sup>	DC to 15 kHz	2.5	±15	Non-cooled/TE-cooled type InGaAs (G12180/G12181/G12182/G12183 series)

## Accessories

- Instruction manual
- Power cable A4372-02  
(with 4-pin connector for amplifier connection, the other side: unterminated wire, 2 m)

## Required power supply specifications

- C4159 series: ±15 V ± 0.5
- Current capacity: 1.5 times or more of amplifier's maximum current consumption
- Ripple noise: 5 mVp-p or less
- Analog power supply only  
Recommended DC power supply (example): PW18-3AD [TEXIO], E3630A [Keysight Technologies]

## Absolute maximum ratings (Ta= 25 °C)

Parameter	Value	Unit
Supply voltage	±18.0 max.	V
Operating temperature*	0 to +40	°C
Storage temperature*	-20 to +70	°C

\* No dew condensation. When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

# Infrared detector modules with preamp

These modules integrate a preamp with an infrared detector of various types. They can detect infrared light simply by connecting a DC power supply.

(Typ.)

Type	Type no.	Detector (type no.)	Photosensitive area (mm)	Cooling	Measurement condition	Cutoff wavelength (μm)	Peak sensitivity wavelength (μm)	Photo
					Chip temperature (°C)			
TE-cooled type	<a href="#">C17212-011</a> 	InAsSb (P16112-011MA)	0.7 × 0.7	Non-cooled	+25	5.3	4.1	
	<a href="#">C17213-011</a> 	InAsSb (P16113-011MN)				8.3	6.5	
	<a href="#">C17214-011</a> 	InAsSb (P16114-011MN)				11	7.4	
	<a href="#">C12483-250</a>	InGaAs (G12180-250A)	φ5	TE-cooled	-15	1.66	1.55	
	<a href="#">C12485-210</a>	InGaAs (G12182-210K)	φ1			2.05	1.95	
	<a href="#">C12486-210</a>	InGaAs (G12183-210K)				2.56	2.3	
	<a href="#">C12492-210</a>	InAs (P10090-21)	φ1		-28	3.45	3.25	
	<a href="#">C12494-222S</a>	InAsSb (P13243-222MS)	2 × 2		-28	4.1	5.1	
	<a href="#">C12494-210S</a>	InAsSb (P11120-201)	φ1			5.9	4.9	
	<a href="#">C12494-210M</a>	InAsSb (P12691-201G)				8.3	6.7	
	<a href="#">C12494-211L</a>	InAsSb (P13894-211MA)	1 × 1			10.2	5.6	

# Infrared detector modules with preamp

These modules integrate a preamp with an infrared detector of various types. They can detect infrared light simply by connecting a DC power supply. High sensitivity is achieved by cooling the chip to -196 °C using a metal dewar.

(Typ.)

Type	Type no.	Detector (type no.)	Photosensitive area (mm)	Cooling	Measurement condition	Cutoff wavelength (μm)	Peak sensitivity wavelength (μm)	Photo
					Chip temperature (°C)			
Metal dewar type	<a href="#">G7754-01</a>	InGaAs (G12183-010)*1	φ1	Liquid nitrogen	-196	2.4	2.0	
	<a href="#">G7754-03</a>	InGaAs (G12183-030)*1	φ3					
	<a href="#">P7751-01</a> *2	InSb (P5968-060)	φ0.6			5.5	5.3	
	<a href="#">P7751-02</a> *2	InSb (P5968-200)	φ2					

\*1: Chip

\*2: FOV=60°

# Photodiode modules

These high accuracy photodetectors have a high/low 2-range switching function.

Type no.	Spectral response range (μm)	Peak sensitivity wavelength (μm)	Detector	Photosensitive area (mm)	Cooling	Photo
<a href="#">C10439-10</a>	0.5 to 1.7	1.55	InGaAs	φ1	Non-cooled	
<a href="#">C10439-11</a>	0.5 to 1.7	1.55	InGaAs	φ3		
<a href="#">C10439-15</a>	0.32 to 2.6	0.94	Si	2.4 × 2.4		
		2.3	InGaAs	φ1		

- **Technical notes**

- [Compound semiconductor photosensors](#)
  - [Thermopile detectors](#)

- **Precautions**

- [Disclaimer](#)
  - [Safety consideration](#)
  - [Metal, ceramic, plastic package products](#)
  - [Unsealed products](#)
  - [Surface mount type products](#)
  - [Compound opto-semiconductors \(photosensors, light emitters\)](#)

- **[Inquiries from online](#)**

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**www.hamamatsu.com**

- Information described in this material is current as of February 2025.
- Product specifications are subject to change without prior notice due to improvements or other reasons. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

## **HAMAMATSU PHOTONICS K.K.**

KIRD0001E20 Feb. 2025 DN

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